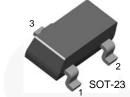


August 2015

BC846 / BC847 / BC848 / BC850 NPN Epitaxial Silicon Transistor

Features

- Switching and Amplifier Applications
- · Suitable for Automatic Insertion in Thick and Thin-film Circuits
- Low Noise: BC850
- Complement to BC856, BC857, BC858, BC859, and BC860



1. Base 2. Emitter 3. Collector

Ordering Information(1)

Part Number	Marking	Package	Packing Method	
BC846AMTF	8AA	SOT-23 3L	Tape and Reel	
BC846BMTF	8AB	SOT-23 3L	Tape and Reel	
BC846CMTF	8AC	SOT-23 3L	Tape and Reel	
BC847AMTF	8BA	SOT-23 3L	Tape and Reel	
BC847BMTF	8BB	SOT-23 3L	Tape and Reel	
BC847CMTF	8BC	SOT-23 3L	Tape and Reel	
BC848BMTF	8CB	SOT-23 3L	Tape and Reel	
BC848CMTF	8CC	SOT-23 3L	Tape and Reel	
BC850AMTF	8EA	SOT-23 3L	Tape and Reel	
BC850CMTF	8EC	SOT-23 3L	Tape and Reel	

Note:

1. Affix "-A,-B,-C" means h_{FE} classification. Affix "-M" means SOT-23 package. Affix "-TF" means the tape and reel type packing.

1

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parameter		Value	Unit	
		BC846	80		
V_{CBO}	Collector-Base Voltage	BC847 / BC850	50	V	
		BC848	30		
		BC846	65		
V_{CEO}	Collector-Emitter Voltage	BC847 / BC850	45	V	
		BC848	30		
V	Emitter Bose Voltage	BC846 / BC847	6	V	
V _{EBO} Emitter-Base Vo	Emitter-Base Voltage	BC848 / BC850	5	v	
I _C	Collector Current (DC)		100	mA	
TJ	Junction Temperature		150	°C	
T _{STG}	Storage Temperature Range		-65 to +150	°C	

Thermal Characteristics(2)

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Value	Unit
D	Power Dissipation	310	mW
P _D	Derate Above 25°C	2.48	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	403	°C/W

Note:

2. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics(3)

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter		Conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector Cut-Off Current		$V_{CB} = 30 \text{ V}, I_{E} = 0$			15	nA
h _{FE}	DC Current Gain		$V_{CE} = 5 \text{ V}, I_{C} = 2 \text{ mA}$	110		800	
\/(cat)	Collector-Emitter Saturation Voltage		$I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$		90	250	mV
vCE(sat)			$I_C = 100 \text{ mA}, I_B = 5 \text{ mA}$		200	600	
\/(eat)	V _{BE} (sat) Collector-Base Saturation Voltage		$I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$		700		mV
v _{BE} (sat)			$I_C = 100 \text{ mA}, I_B = 5 \text{ mA}$		900		111 V
\/(on)	V _{BE} (on) Base-Emitter On Voltage		$V_{CE} = 5 \text{ V}, I_{C} = 2 \text{ mA}$	580	660	700	mV
vBE(OII)			$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$			720	1110
f _T	Current Gain Bandwidth Product		$V_{CE} = 5 \text{ V, } I_{C} = 10 \text{ mA,}$ f = 100 MHz		300		MHz
C _{ob}	Output Capacitance		$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		3.5	6.0	pF
C _{ib}	Input Capacitance		$V_{EB} = 0.5 \text{ V}, I_{C} = 0, f = 1 \text{ MHz}$		9		pF
		BC846 / BC847 / BC848	$V_{CE} = 5 \text{ V}, I_{C} = 200 \mu\text{A},$		2.0	10.0	
NF	Noise	BC850	$R_G = 2 k\Omega, f = 1 kHz$		1.2	4.0	dB
Figur	Figure BC8	BC850	$V_{CE} = 5 \text{ V}, I_{C} = 200 \mu\text{A}, R_{G} = 2 \text{ k}\Omega, f = 30 \text{ to } 15000 \text{ Hz}$		1.4	3.0	QD

Note:

3. Pulse test: pulse width $\leq 300~\mu s,$ duty cycle $\leq 2\%$

h_{FE} Classification

Classification A		В	С
h _{FE}	110 ~ 220	200 ~ 450	420 ~ 800

Typical Performance Characteristics

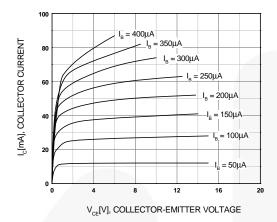


Figure 1. Static Characteristic

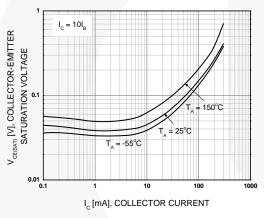


Figure 3. Currector-Emitter Saturation Voltage

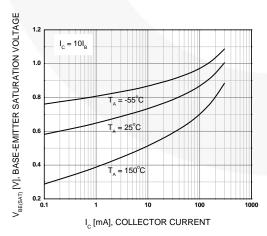


Figure 5. Base-Emitter Saturation Voltage

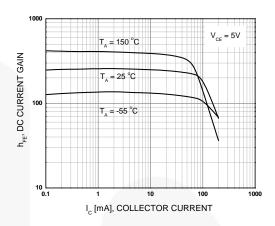


Figure 2. DC Current Gain

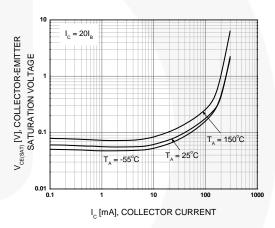


Figure 4. Currector-Emitter Saturation Voltage

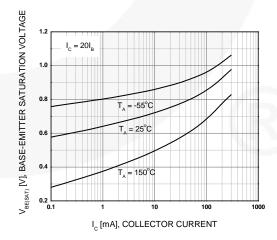


Figure 6. Base-Emitter Saturation Voltage

Typical Performance Characteristics (Continued)

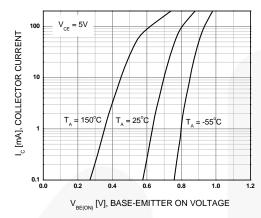


Figure 7. Base-Emitter On Voltage

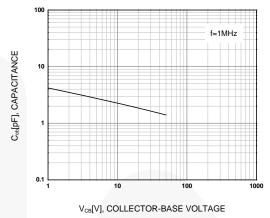


Figure 8. Collector Output Capacitance

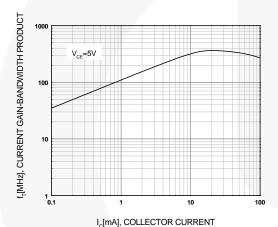
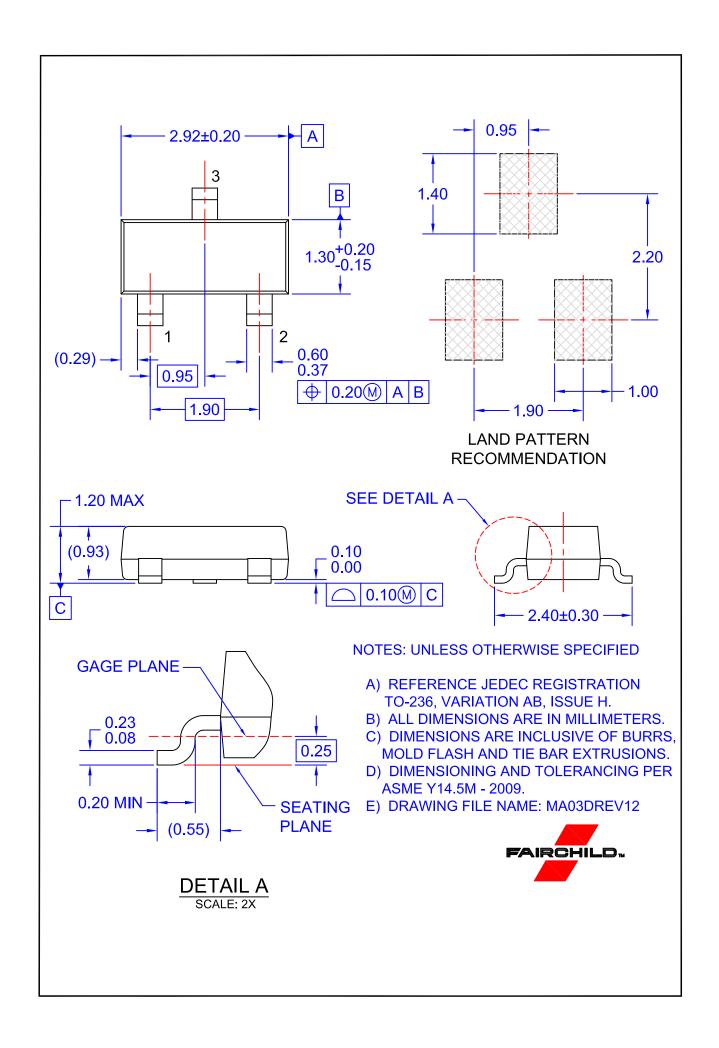


Figure 9. Current Gain Bandwidth Product







TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower™ F-PFS™ AttitudeEngine™ FRFET®

Global Power ResourceSM Awinda[®] AX-CAP®*

GreenBridge™ BitSiC™ Green FPS™ Build it Now™ Green FPS™ e-Series™

CorePLUS™ Gmax™ CorePOWER™ $\mathsf{GTO}^{\mathsf{TM}}$ CROSSVOLT™ IntelliMAX™ CTL™ ISOPLANAR™

Current Transfer Logic™ Making Small Speakers Sound Louder

DEUXPEED® and Better™ Dual Cool™ MegaBuck™ EcoSPARK® MIČROCOUPLER™ EfficientMax™ MicroFET™

MicroPak™ MicroPak2™ MillerDrive™ MotionMax™ Fairchild Semiconductor® MotionGrid® FACT Quiet Series™

MTi[®] FACT[®] MTx® FastvCore™ MVN® FETBench™ mWSaver® FPS™ OptoHiT™ OPTOLOGIC® OPTOPLANAR®

Power Supply WebDesigner™ PowerTrench®

PowerXSTI

Programmable Active Droop™

OFFT QS™ Quiet Series™ RapidConfigure™

Saving our world, 1mW/W/kW at a time™

SignalWise™ SmartMax™ SMART START™

Solutions for Your Success™

SPM® STEALTH™ SuperFET® SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS® SyncFET™ Sync-Lock™

SYSTEM SYSTEM

TinyBoost[®] TinyBuck[®] TinyCalc™ TinyLogic[®] TINYOPTO™ TinvPower™ TinyPWM™ TinyWire™ TranSiC™

TriFault Detect™ TRUECURRENT®* սSerDes™

UHC Ultra FRFET™ UniFET™ VCX™ VisualMax™

VoltagePlus™ XSTM. Xsens™ 仙童®

* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

ESBC™

-®

Fairchild®

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR <u>AIRCHILDSEMI.COM.</u> FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

Unless otherwise specified in this data sheet, this product is a standard commercial product and is not intended for use in applications that require extraordinary levels of quality and reliability. This product may not be used in the following applications, unless specifically approved in writing by a Fairchild officer: (1) automotive or other transportation, (2) military/aerospace, (3) any safety critical application - including life critical medical equipment - where the failure of the Fairchild product reasonably would be expected to result in personal injury, death or property damage. Customer's use of this product is subject to agreement of this Authorized Use policy. In the event of an unauthorized use of Fairchild's product, Fairchild accepts no liability in the event of product failure. In other respects, this product shall be subject to Fairchild's Worldwide Terms and Conditions of Sale, unless a separate agreement has been signed by both Parties.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com,

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Definition of Terms					
Datasheet Identification	Product Status	Definition			
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.			
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.			
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.			
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.			

Rev 177